Electron recombination, photoionization, and scattering via many-electron compound resonances

V. A. Dzuba,¹ V. V. Flambaum,¹ G. F. Gribakin,² C. Harabati,¹ and M. G. Kozlov^{1,3,4}

¹School of Physics, The University of New South Wales, Sydney NSW 2052, Australia

²School of Mathematics and Physics, Queen's University, Belfast BT7 1NN, Northern Ireland, United Kingdom

³Petersburg Nuclear Physics Institute, Gatchina 188300, Russia

⁴St. Petersburg Electrotechnical University "LETI", Prof. Popov Str. 5, 197376 St. Petersburg, Russian Federation

(Received 4 November 2013; published 30 December 2013)

Highly excited eigenstates of atoms and ions with open f shell are chaotic superpositions of thousands, or even millions, of Hartree-Fock determinant states. The interaction between dielectronic and multielectronic configurations leads to the broadening of dielectronic recombination resonances and relative enhancement of photon emission due to opening of thousands of radiative decay channels. The radiative yield is close to 100% for electron energy ≤ 1 eV and rapidly decreases for higher energies due to opening of many autoionization channels. The same mechanism predicts suppression of photoionization and relative enhancement of the Raman scattering. Results of our calculations of the recombination rate are in agreement with the experimental data for W²⁰⁺ and Au²⁵⁺.

DOI: 10.1103/PhysRevA.88.062713

PACS number(s): 34.80.Lx, 31.10.+z, 34.10.+x

I. CHAOS AND STATISTICAL THEORY

It is well known that a long-time behavior of a classical chaotic system is unpredictable due to exponential divergence of phase-space trajectories. Any small changes in the initial conditions or computer rounding errors are exponentially enhanced over time. However, the chaos makes statistical predictions possible. For example, we cannot predict the motion of a specific molecule in a gas, but we can predict the diffusion coefficients, distribution of velocities, pressure, etc.

In isolated quantum many-body systems chaos emerges due to the exponential growth in the energy-level density caused by the increase in the number of "active" particles. It follows the increase in the energy of the system, which allows more particles to be excited into unoccupied orbitals. Indeed, the number of ways to distribute *n* fermions over *m* orbitals is exponentially large for $n,m \gg 1$, even when *n* itself is not very large.

By distributing the particles among orbitals in different ways one generates the Slater determinant states $|i\rangle$ (configuration states) from some mean-field, e.g., Hartree-Fock, single-particle orbitals. These states serve as the basis for finding the *eigenstates* $|n\rangle = \sum_{i} C_{i}^{(n)} |i\rangle$. When the residual interaction between the particles exceeds the energy spacing between the basis states coupled by this interaction, the eigenstates become chaotic superpositions of thousands or even millions of basis states $|i\rangle$.

The expansion coefficients $C_i^{(n)}$ in such superpositions behave largely as independent random variables. They are, however, subject to the normalization condition $\sum_i |C_i^{(n)}|^2 =$ $\sum_n |C_i^{(n)}|^2 = 1$. Also, the variance of $C_i^{(n)}$ displays a systematic variation with the energy of the eigenstates and basis states [1,2]:

$$\overline{\left|C_{i}^{(n)}\right|^{2}} = \frac{D}{2\pi} \frac{\Gamma_{\rm spr}}{(E_{n} - E_{i})^{2} + \Gamma_{\rm spr}^{2}/4}.$$
 (1)

Here *D* is the mean level spacing between the basis states (or eigenstates) with a given total angular momentum and parity J^p , and $\Gamma_{spr} = 2\pi \overline{H_{ik}^2}/D$ is the *spreading width*. It is

determined by the size of the off-diagonal matrix elements of the Hamiltonian H_{ik} which mix the basis states.

Many-body quantum chaos occurs in excited states of all medium and heavy nuclei [1,2]. It is also typical in atoms and ions with open f shells. In particular, their excitation spectra demonstrate characteristic Wigner-Dyson level spacing statistics, and the statistics of electromagnetic transition amplitudes is close to Gaussian, which are both signatures of quantum chaos [3–6].

"Exact" calculations of the chaotic eigenstates (compound states) are impossible in principle, since all minor perturbations (e.g., higher-order correlations and relativistic effects) are enhanced due to exponentially small level spacings, and completely change the eigenstates. In this case, however, one can use statistical theory to predict physical quantities averaged over a small energy interval containing many compound states. In the problem of electron recombination with ions like W^{20+} and Au^{25+} such averaging occurs naturally, and the result of the statistical calculation should match the experimental observation. Indeed, due to a large number of decay channels, the widths of the compound states are two orders of magnitude greater than the exponentially small spacing between neighboring compound states. As a result, the cross section at any given energy typically contains contributions of 10^2 or more individual resonances.

Note that due to the extremely strong configuration mixing, approximate quantum numbers such as the orbital occupation numbers (which define configurations, e.g., $4f^{2}6s5d$), the number of excited electrons n_e , and the total orbital angular momentum L and spin S are not defined for the compound states. One can only consider average values and distributions for these parameters. For example, the dependence of the electron orbital occupation numbers on the orbital energy ε in the chaotic compound states of atoms and ions is close to the Fermi-Dirac distribution $n(\varepsilon, \mu, T)$, where the chemical potential $\mu(E)$ and the effective temperature T(E) depend on the total excitation energy E [3,4,6].

Earlier papers [7,8] and reviews [9,10] present the development of the statistical theory for the matrix elements between chaotic compound states. This theory enables one to

calculate mean values of orbital occupation numbers, squared electromagnetic amplitudes, electronic and electromagnetic widths, and enhancement of weak interactions in chaotic excited states of nuclei, atoms, and multicharged ions [3-13].

II. ELECTRON-ION RECOMBINATION

A. Chaotic compound resonances and dielectronic doorway states

In most ions except bare ones the electron-ion recombination rate is enhanced by dielectronic recombination (DR). In this process the incident electron excites a target electron to form a quasistationary doubly excited state which then emits a photon, completing the radiative electron capture [14]. The DR mechanism often dominates over the direct radiative recombination (RR), and has been the subject of intense theoretical and experimental work. Experimentally, much progress has been due to the use of ion storage rings and electron-beam ion traps [15–17]. On the theory side, a number of computational approaches have been used successfully to describe DR for many simpler ions and to produce data for plasma modeling (see [18–27] and references therein).

For more complex targets such as U^{28+} or W^{20+} , conventional DR approaches severely underestimate measured recombination rates [28,29]. Experiment shows that the recombination rates at low ($\sim 1 \text{ eV}$) electron energies in these ions and in Au²⁵⁺ exceed the direct RR rates by two orders of magnitude. At the same time the rates do not show the sharp resonance structure normally associated with DR [30-32]. Reference [4] explained this phenomenon as being due to electron capture in *multiply* excited, strongly mixed, chaotic eigenstates. It is caused by the open-shell structure of the compound ion Au²⁴⁺ and the electronic orbital spectrum with no large gaps. These features lead to a very dense spectrum of multiply excited states, as described in Sec. I. The subsequent calculation [5] based on the statistical theory provided a quantitative explanation of the enhanced recombination rates near threshold.

Experimentally, direct evidence of *trielectronic* recombination (i.e., via resonances with three excited electrons) was obtained for Be-like ions $(N^{3+}, O^{4+}, Cl^{13+})$ [33,34]. In these systems electron capture into a Rydberg state was accompanied by simultaneous $2s^2 \rightarrow 2p^2$ excitations. Additionally, trielectronic and quadruelectronic recombination was observed in Li-like to N-like ions of Ar, Fe, and Kr [35–37]. It involved intershell excitations leading to $1s^{-1}2p^3$ and $1s^{-1}2p^4$ resonances. However, in the case of chaotic compound resonances one cannot separate dielectronic, trielectronic, or any other capture process into a resonance with a fixed number of excited electrons. Indeed, a compound state is a chaotic mixture of the states with two, three, four, and even five excited electrons, and contributions from all of these configurations are mixed and interfere in the capture amplitude.

Nevertheless, dielectronic states play a special role. To start with, consider the temporal picture of radiative recombination. In the first step, the incident electron collides with an ion and excites one electron (by exchanging a virtual photon) and produces an intermediate state with two excited electrons. We call such state a *doorway state*. This is followed by a "chain reaction" in which one of the excited electrons collides with ground-state electrons and excites them. This process continues until all energy of the incident electron equilibrates through excitation of as many electrons as possible. Thus the doorway state (with two excited electrons) "decays" into other configurations with more excited electrons. This fast internal decay on time scales $\tau \sim \hbar/\Gamma_{spr}$ is characterized by the spreading width Γ_{spr} [see Eq. (1)], which is several orders of magnitude greater than the autoionization or radiative widths of the dielectronic state. The notion of the spreading width is somewhat similar to the quasiparticle width in condensed-matter systems where quasiparticles also decay into other internal excitations of the system.

Due to the time-energy uncertainty relation the temporal picture cannot be used if the energy of the system is fixed. In this case the configuration mixing picture is more appropriate. According to this, the dielectronic doorway states are present as components in every chaotic compound state, and their weights (1) determine the probability of electron capture into the compound state. The autoionization width of a compound state *n* is $\Gamma_n^{(a)} = \sum_d \Gamma_d^{(a)} |C_d^{(n)}|^2$, where the sum is taken over the dielectronic doorway states whose autoionization widths $\Gamma_d^{(a)}$ are calculated at the incident electron energy ε . By the normalization condition $\sum_{n} |C_d^{(n)}|^2 = 1$, the sum of the autoionization widths of the compound resonances is equal to the sum of the autoionization widths of the doorway states. Therefore, the energy-averaged total resonance cross section may be approximately described by treating the dielectronic resonances as quasistationary states with the width Γ_{spr} (see Sec. III A).

B. Fluorescence yield

The capture or reemission of the electron is mediated by the dielectronic doorway states. However, they are not sufficient for describing the process of radiative capture, since a photon can be emitted at any stage of the "chain reaction." Three-electron, four-electron, and five-electron excited states also radiate, and their total weight in a compound state is several orders of magnitude greater than that of the dielectronic states. As a result, the radiative width $\Gamma_n^{(r)}$ of the compound state is enhanced relative to its autoionization width (since electron emission happens directly from dielectronic states only). As a result, compound states display strongly enhanced fluorescence yields $\omega_f = \Gamma_n^{(r)} / \Gamma_n$, where $\Gamma_n = \sum_f \Gamma_{n \to f}^{(a)} + \Gamma_n^{(r)}$ is the total width of the compound resonance *n*, and the sum is over all autoionization channels (i.e., autoionization to the ground and excited states of the ion).

In Refs. [5,11] we argued that the fluorescence yield at low incident electron energies is close to 100%. Indeed, near threshold only one autoionization channel (with decay to the ground state) is available, making the autoionization width much smaller than the total radiative width which includes thousands of open photoemission channels. In this case it is sufficient to calculate the total resonant capture cross section to describe recombination. However, at higher electron energies, hundreds of autoionization channels are open (since there are many low-lying excited states in ions with an open 4fshell), and the calculation of the fluorescence yield becomes necessary. In the present work we show how this can be done within the statistical theory.

III. CALCULATIONS

A. Theory

The energy-averaged total cross section for electron recombination through the compound resonances is (see, e.g., [11])

$$\overline{\sigma}_r = \frac{\pi^2}{k^2} \sum_{J^p} \frac{2J+1}{(2J_i+1)} \rho_{J^p} \left\langle \frac{\Gamma_{J^p}^{(r)} \Gamma_{J^p \to i,\varepsilon}^{(a)}}{\Gamma_{J^p}} \right\rangle, \qquad (2)$$

where k is the wave number of the incident electron and *i* denotes the initial (ground) state of the *N*-electron target ion with angular momentum J_i . The sum is over the angular momentum and parity of the compound states, $\rho_{J^p} = 1/D_{J^p}$ is the level density of these states for a given J^p in the excited (N + 1)-electron ion formed by the electron capture, and $\langle \cdots \rangle$ denotes averaging over an energy interval $\Delta \varepsilon \gg D_{J^p}$.

If we assume that the factor in brackets for the dominant J^p in (2) is approximately the same, we obtain

$$\overline{\sigma}_r = \frac{\pi^2}{k^2} \frac{\Gamma_n^{(r)} \Gamma_{n \to i,\varepsilon}^{(a)}}{(2J_i + 1)\Gamma_n} \rho = \overline{\sigma}_c \omega_f, \qquad (3)$$

where $\Gamma_n^{(r)}$, $\Gamma_n^{(a)}$, and Γ_n are the average widths of the compound states at energy ε , $\rho = \sum_{J^p} (2J+1)\rho_{J^p}$ is the total level density of the compound states (which can be found without constructing the states with definite J^p from the Hartree-Fock determinant states), $\omega_f = \Gamma_n^{(r)} / \Gamma_n$ is the average fluorescence yield, and

$$\overline{\sigma}_c = \frac{\pi^2}{k^2} \frac{\Gamma_{n \to i,\varepsilon}^{(a)}}{(2J_i + 1)} \rho \tag{4}$$

is the energy-averaged total cross section for electron capture into the compound resonances. It is given explicitly by the sum over the dielectric doorways (see [5]):

$$\overline{\sigma}_{c} = \frac{\pi^{2}}{k^{2}} \sum_{abh,lj} \frac{\Gamma_{\rm spr}}{\left(E_{c_{i}} + \varepsilon - E_{c_{i} \to \bar{h},a,b}\right)^{2} + \Gamma_{\rm spr}^{2}/4} \sum_{\lambda} \frac{\langle a, b \| V_{\lambda} \| h, \varepsilon l j \rangle}{2\lambda + 1} \left[\langle a, b \| \hat{V}_{\lambda} \| h, \varepsilon l j \rangle - (2\lambda + 1) \right] \\ \times \sum_{\lambda'} (-1)^{\lambda + \lambda' + 1} \left\{ \begin{array}{l} \lambda & j_{a} & j \\ \lambda' & j_{b} & j_{h} \end{array} \right\} \langle b, a \| \hat{V}_{\lambda'} \| h, \varepsilon l j \rangle \right] \frac{n_{h}}{2j_{h} + 1} \left(1 - \frac{n_{a}}{2j_{a} + 1} \right) \left(1 - \frac{n_{b}}{2j_{b} + 1} \right).$$
(5)

Here E_{c_i} is the energy of the ground-state target ion with configuration c_i and $E_{c_i \rightarrow \bar{h}, a, b}$ is the energy of the dielectronic doorway obtained from c_i by making a hole in orbital h and adding electrons in orbitals a and b; $E_{c_i} + \varepsilon - E_{c_i \rightarrow \bar{h}, a, b} \approx$ $\varepsilon + \varepsilon_h - \varepsilon_a - \varepsilon_b + Q$, where ε_a , ε_b , and ε_h are the orbital energies and Q is the difference in the Coulomb interaction energies (see, e.g., [4]); n_a , n_b , and n_h are the average occupation numbers of the corresponding orbitals in c_i . The two terms in square brackets in Eq. (5) represent the direct and exchange contributions,

$$\begin{aligned} \langle a,b \| V_{\lambda} \| h,c \rangle \\ &= \sqrt{[j_a][j_b][j_h][j_c]} \xi(l_a + l_c + \lambda) \xi(l_b + l_h + \lambda) \\ &\times \begin{pmatrix} \lambda & j_a & j_c \\ 0 & -\frac{1}{2} & \frac{1}{2} \end{pmatrix} \begin{pmatrix} \lambda & j_b & j_h \\ 0 & -\frac{1}{2} & \frac{1}{2} \end{pmatrix} R_{\lambda}(a,b;h,c) \end{aligned}$$

is the reduced Coulomb matrix element, in which $\xi(L) = [1 + (-1)^L]/2$ is the parity selection factor, $[j_a] \equiv 2j_a + 1$, and

$$R_{\lambda}(a,b;h,c) = \iint \frac{r_{<}^{\lambda}}{r_{>}^{\lambda+1}} \left[f_a(r) f_c(r) + g_a(r) g_c(r) \right]$$
$$\times \left[f_b(r') f_h(r') + g_b(r') g_h(r') \right] dr dr'$$

is the radial Coulomb integral, f and g being the upper and lower components of the relativistic radial spinors.

The form of Eq. (5) is similar to the expressions which emerge in the so-called average-configuration approximation [38]. The difference between the two approaches is that in a system with chaotic eigenstates, the averaging that leads to Eq. (5) occurs naturally due to the strong configuration mixing, rather then being introduced by hand to simplify the calculations.

Note that expressions (4) and (5) allow us to calculate $\Gamma_{n \to i,\varepsilon}^{(a)}$. In order to find the fluorescence yield $w_f(\varepsilon)$ we need to calculate the total autoionizing width $\Gamma_n^{(a)} = \sum_f \Gamma_{n \to f,\varepsilon}^{(a)}$, where the sum runs over all states of the target ion with energies $E_f < E_i + \varepsilon$. The expression for the radiative width of the compound state was given in Ref. [5],

$$\Gamma_d^{(r)} = \sum_{a,b} \frac{4\omega_{ba}^3}{3c^3} |\langle a \| d \| b \rangle|^2 \frac{n_b}{2j_b + 1} \left(1 - \frac{n_a}{2j_a + 1} \right), \quad (6)$$

where n_a and n_b are the occupation numbers of orbitals aand b in the compound state at the incident electron energy ε , $\langle a \| d \| b \rangle$ is the reduced single-electron dipole matrix element, and the sum is over a and b such that $\omega_{ba} = \varepsilon_b - \varepsilon_a > 0$. The calculations of the spreading widths give $\Gamma_{spr} \approx 0.5$ a.u. for Au²⁵⁺ [4–6] and 0.68 a.u. for W²⁰⁺ [11].

B. Results

The results of our calculations of the fluorescence yield are shown in Fig. 1. At $\varepsilon \leq 1$ eV the fluorescence yield in the compound states of Au²⁴⁺ is close to unity, but quickly drops to $\omega_f \sim 0.2$.

In Fig. 2 the calculated total resonant capture cross section $\overline{\sigma}_c$ and the recombination cross section $\overline{\sigma}_r$ are compared with the experimental data for W²⁰⁺ [32] and Au²⁵⁺ [31]. To eliminate the strong kinematic dependence the cross sections have been multiplied by k^2/π^2 . Note that the experimental data display large fluctuations and show some unphysical



FIG. 1. (Color online) Calculated fluorescence yields in Au^{24+} and W^{19+} averaged over 1 eV energy interval.

negative values for the recombination rate (due to background subtraction). To reduce these fluctuations we have averaged the experimental data for $(k^2/\pi^2)\sigma_r$ over 1 eV energy interval. We also averaged over 1 eV range the calculated fluorescence yields (see Fig. 1) to reduce fluctuations in the density of states.

In Fig. 3 we compare the results of our calculations of the recombination rate for W^{20+} with raw (un-



FIG. 3. (Color online) Recombination rates for W^{20+} . Solid red line is our theory, dashed black line is the calculation of Ref. [29], and dotted blue line is the experimental data [32].

averaged) experimental data [32] and calculations from Ref. [29].

C. Suppression of photoionization due to chaotic compound resonances

As discussed above, for energies $\lesssim 1 \text{ eV}$ above the ionization threshold the radiative width of a compound state



FIG. 2. (Color online) Reduced cross sections $\sigma k^2/\pi^2$ for electron capture by W²⁰⁺ and Au²⁵⁺, averaged over 1 eV energy intervals to suppress fluctuations. Dotted lines show the calculated total resonant capture ($\overline{\sigma}_c$), solid lines are the calculated recombination cross section $\overline{\sigma}_r = \overline{\sigma}_c \omega_f$, and the dashed lines correspond to the measured recombination cross section for W²⁰⁺ [32] and Au²⁵⁺ [31].

can be much greater than its autoionization width. Besides enhancing recombination, this effect leads to suppression of near-threshold photoionization, since a compound resonance excited by the incident photon will decay primarily by emission of another photon rather than by emitting an electron. Therefore, at these energies the inelastic, Raman photon scattering dominates over the photoionization. Similar to the electron resonant capture, the energy-averaged total photon capture cross section into compound resonances may be approximately described by treating the simple doorway resonances as quasistationary states with the width Γ_{spr} . To obtain the photoionozation cross sections one should multiply the result by the fluorescence yield calculated in the present work. Taking the corresponding ratios of the widths one can also obtain the cross sections for elastic and inelastic (Raman) photon scattering.

IV. CONCLUSIONS

We see that in both electron- and photon-induced processes the interaction between dielectronic and multielectronic configurations leads to broadening of the dielectronic doorway resonances (due to the internal decay) and redistribution of the branching between the "external" decay channels in favor of the photoemission.

In principle, within the statistical theory one can take into account the exact quantum numbers of the dielectronic doorway states (angular momentum and parity). One can even diagonalize the Hamiltonian using the basis of the dielectronic states, and then use the "dielectronic eigenstates" as the doorway states with the weights from Eq. (1). However, the spreading width Γ_{spr} is comparable to the energy spread of a single configuration. Therefore, our present use of the Hartree-Fock (determinant) basis states as doorway states without a definite J should not significantly reduce the accuracy of the approach. A greater possible error in our calculations is due to the uncertainty in the energies of the doorway states corresponding to the transitions to the ground and excited states of the final (N + 1)-electron ion, which are needed to calculate the fluorescence yield. It is likely this uncertainty that leads to a factor of 2 differences between the theoretical and experimental values. However, this discrepancy will be greatly reduced for the Maxwellian, thermally averaged recombination rates at high electron temperatures. Such rates are very important in modeling plasmas in astrophysical environments and thermonuclear reactors, and they are less sensitive to the precise doorway state positions. A deviation from the experimental data may also be due to the presence of the metastable species in the initial ion beam. Significant contributions of such excited ions was pointed to in the experimental work [32].

We presented numerical calculations for W^{20+} and Au^{25+} for which experimental electron recombination data are available [31,32]. Tungsten is a key plasma-facing component of ITER and future fusion reactors. A broad range of tungsten ions from W^{20+} to W^{50+} is a major plasma impurity and a plasma diagnostic tool. Modeling their fractional abundances and emission spectra reveals that available theoretical recombination rates do not accurately describe the experimental temperature dependence [39], and empirical adjustments to the recombination rates were needed to reconcile with the measurements. Clearly, further experimental and theoretical work on those complex systems is required, including the extension of our statistical theory calculations to other tungsten ions.

ACKNOWLEDGMENTS

This work is partly supported by the Australian Research Council and Russian Foundation for Basic Research Grant No. 11-02-00943. We thank S. Schippers and A. Müller for providing experimental data in numerical form.

- A. Bohr and B. Mottelson, *Nuclear Structure* (Benjamin, New York, 1969), Vol. 1.
- [2] V. Zelevinsky, B. A. Brown, M. Frazier, and M. Horoi, Phys. Rep. 276, 85 (1996).
- [3] V. V. Flambaum, A. A. Gribakina, G. F. Gribakin, and M. G. Kozlov, Phys. Rev. A **50**, 267 (1994); V. V. Flambaum, A. A. Gribakina, and G. F. Gribakin, *ibid.* **54**, 2066 (1996); **58**, 230 (1998); A. A. Gribakina, V. V. Flambaum, and G. F. Gribakin, Phys. Rev. E **52**, 5667 (1995); V. V. Flambaum, A. A. Gribakina, G. F. Gribakin, and I. V. Ponomarev, *ibid.* **57**, 4933 (1998); Physica D **131**, 205 (1999).
- [4] G. F. Gribakin, A. A. Gribakina, and V. V. Flambaum, Aust. J. Phys. 52, 443 (1999); see also arXiv:physics/9811010.
- [5] V. V. Flambaum, A. A. Gribakina, G. F. Gribakin, and C. Harabati, Phys. Rev. A 66, 012713 (2002).
- [6] G. F. Gribakin and S. Sahoo, J. Phys. B 36, 3349 (2003).
- [7] V. V. Flambaum, Phys. Scr., T 46, 198 (1993).
- [8] V. V. Flambaum and O. K. Vorov, Phys. Rev. Lett. 70, 4051 (1993).

- [9] V. V. Flambaum and G. F. Gribakin, Prog. Part. Nucl. Phys. 35, 423 (1995).
- [10] V. V. Flambaum and G. F. Gribakin, Philos. Mag. B 80, 2143 (2000).
- [11] V. A. Dzuba, V. V. Flambaum, G. F. Gribakin, and C. Harabati, Phys. Rev. A 86, 022714 (2012).
- [12] O. P. Sushkov and V. V. Flambaum, Usp. Fiz. Nauk. 136, 3 (1982) [Sov. Phys. Usp. 25, 1 (1982)].
- [13] V. V. Flambaum, G. F. Gribakin, and F. M. Izrailev, Phys. Rev. E 53, 5729 (1996); V. V. Flambaum, F. M. Izrailev, and G. Casati, *ibid.* 54, 2136 (1996); V. V. Flambaum and F. M. Izrailev, *ibid.* 55, R13 (1997); 56, 5144 (1997); 61, 2539 (2000); 64, 036220 (2001); 64, 026124 (2001).
- [14] H. S. W. Massey and D. R. Bates, Rep. Prog. Phys. 9, 62 (1942).
- [15] A. Müller, Philos. Trans. R. Soc. London 357, 1279 (1999);
 Adv. At. Mol. Phys. 55, 293 (2008).
- [16] Y. Zou, J. R. Crespo López-Urrutia, and J. Ullrich, Phys. Rev. A 67, 042703 (2003).
- [17] P. Beiersdorfer, Can. J. Phys. 86, 1 (2008).

- [18] S. N. Nahar and A. K. Pradhan, Phys. Rev. A 49, 1816 (1994).
- [19] Y. Hahn, Rep. Prog. Phys. **60**, 691 (1997).
- [20] E. Lindroth, H. Danared, P. Glans, Z. Pešić, M. Tokman, G. Vikor, and R. Schuch, Phys. Rev. Lett. 86, 5027 (2001).
- [21] M. Tokman, N. Eklow, P. Glans, E. Lindroth, R. Schuch, G. Gwinner, D. Schwalm, A. Wolf, A. Hoffknecht, A. Müller, and S. Schippers, Phys. Rev. A 66, 012703 (2002).
- [22] N. R. Badnell, M. G. O'Mullane, H. P. Summers, Z. Altun, M. A. Bautista, J. Colgan, T. W. Gorczyca, D. M. Mitnik, M. S. Pindzola, and O. Zatsarinny, Astron. Astrophys. 406, 1151 (2003).
- [23] E. Behar, V. L. Jacobs, J. Oreg, A. Bar-Shalom, and S. L. Haan, Phys. Rev. A 69, 022704 (2004).
- [24] M. F. Gu, Can. J. Phys. 86, 675 (2008).
- [25] D. Nikolic, T. W. Gorczyca, and N. R. Badnell, Phys. Rev. A 79, 012703 (2009).
- [26] C. P. Ballance, S. D. Loch, M. S. Pindzola, and D. C. Griffin, J. Phys. B 43, 205201 (2010).
- [27] N. R. Badnell, Comput. Phys. Commun. 182, 1528 (2011).
- [28] D. M. Mitnik, M. S. Pindzola, F. Robicheaux, N. R. Badnell, O. Uwira, A. Müller, A. Frank, J. Linkemann, W. Spies, N. Angert, P. H. Mokler, R. Becker, M. Kleinod, S. Ricz, and L. Empacher, Phys. Rev. A 57, 4365 (1998).
- [29] N. R. Badnell, C. P. Ballance, D. C. Griffin, and M. O'Mullane, Phys. Rev. A 85, 052716 (2012).
- [30] O. Uwira, A. Müller, W. Spies, J. Linkemann, A. Frank, T. Cramer, L. Empacher, R. Becker, M. Kleinod, P. H. Mokler, J. Kenntner, A. Wolf, U. Schramm, T. Schussler, D. Schwalm, and D. Habs, Hyperfine Interact. **99**, 295 (1996).

- [31] A. Hoffknecht, O. Uwira, S. Schennach, A. Frank, J. Haselbauer, W. Spies, N. Angert, P. H. Mokler, R. Becker, M. Kleinod, S. Schippers, and A. Müller, J. Phys. B 31, 2415 (1998).
- [32] S. Schippers, D. Bernhardt, A. Müller, C. Krantz, M. Grieser, R. Repnow, A. Wolf, M. Lestinsky, M. Hahn, O. Novotný, and D. W. Savin, Phys. Rev. A 83, 012711 (2011).
- [33] M. Schnell, G. Gwinner, N. R. Badnell, M. E. Bannister, S. Böhm, J. Colgan, S. Kieslich, S. D. Loch, D. Mitnik, A. Müller, M. S. Pindzola, S. Schippers, D. Schwalm, W. Shi, A. Wolf, and S.-G. Zhou, Phys. Rev. Lett. **91**, 043001 (2003).
- [34] M. Fogle, N. R. Badnell, P. Glans, S. D. Loch, S. Madzunkov, Sh. A. Abdel-Naby, M. S. Pindzola, and R. Schuch, Astron. Astrophys. 442, 757 (2005).
- [35] C. Beilmann, O. Postavaru, L. H. Arntzen, R. Ginzel, C. H. Keitel, V. Mäckel, P. H. Mokler, M. C. Simon, H. Tawara, I. I. Tupitsyn, J. Ullrich, J. R. Crespo López-Urrutia, and Z. Harman, Phys. Rev. A 80, 050702 (2009).
- [36] C. Beilmann, P. H. Mokler, S. Bernitt, C. H. Keitel, J. Ullrich, J. R. Crespo López-Urrutia, and Z. Harman, Phys. Rev. Lett. 107, 143201 (2011).
- [37] C. Beilmann, Z. Harman, P. H. Mokler, S. Bernitt, C. H. Keitel, J. Ullrich, and J. R. Crespo López-Urrutia, arXiv:1306.1029.
- [38] M. S. Pindzola, D. C. Griffin, and C. Bottcher, in *Atomic Processes in Electron-ion and Ion-ion Collisions*, edited by F. Brouillard, NATO Advanced Studies Institute, Series B: Physics (Plenum Press, New York, 1986), Vol. 145, p. 75.
- [39] T. Pütterich, R. Neu, R. Dux, A. D. Whiteford, M. G. OMullane, and the ASDEX Upgrade Team, Plasma Phys. Control. Fusion 50, 085016 (2008).